











**CSD19536KCS** 

SLPS485B - JANUARY 2014-REVISED OCTOBER 2014

# CSD19536KCS 100 V N-Channel NexFET™ Power MOSFET

#### **Features**

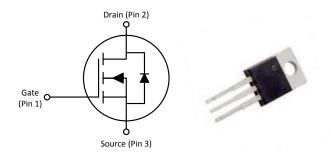
- Ultra-Low Q<sub>a</sub> and Q<sub>ad</sub>
- Low Thermal Resistance
- Avalanche Rated
- Pb-Free Terminal Plating
- **RoHS Compliant**
- Halogen Free
- TO-220 Plastic Package

## Applications

- Secondary Side Synchronous Rectifier
- Motor Control

#### **Description**

This 100 V, 2.3 mΩ, TO-220 NexFET™ power MOSFET is designed to minimize losses in power conversion applications.



#### **Product Summary**

$T_A = 25^\circ$	С	TYPICAL VA	UNIT			
$V_{DS}$	Drain-to-Source Voltage 100					
$Q_g$	Gate Charge Total (10 V) 118					
Q <sub>gd</sub>	Gate Charge Gate to Drain	17	nC			
0	Drain-to-Source On-Resistance	$V_{GS} = 6 V$	2.5	mΩ		
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = 10 V 2.3		mΩ		
V <sub>GS(th)</sub>	Threshold Voltage	2.5	V			

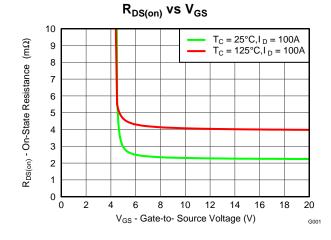
#### **Ordering Information**

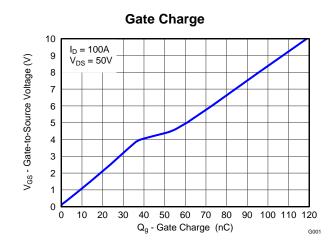
Device	Package	Media	Qty	Ship
CSD19536KCS	TO-220 Plastic Package	Tube	50	Tube

#### **Absolute Maximum Ratings**

$T_A = 2$	5°C	VALUE	UNIT						
$V_{\text{DS}}$	Drain-to-Source Voltage	100	V						
$V_{GS}$	Gate-to-Source Voltage	±20	V						
	Continuous Drain Current (Package limited)	150							
I <sub>D</sub>	Continuous Drain Current (Silicon limited), $T_C = 25^{\circ}C$	259	Α						
	Continuous Drain Current (Silicon limited), $T_C = 100$ °C	183							
$I_{DM}$	Pulsed Drain Current (1)	400	Α						
$P_D$	Power Dissipation	375	W						
T <sub>J</sub> , T <sub>stg</sub>	Operating Junction and Storage Temperature Range	-55 to 175	°C						
E <sub>AS</sub>	Avalanche Energy, single pulse $I_D$ = 127 A, L = 0.1 mH, $R_G$ = 25 $\Omega$	806	mJ						

(1) Max  $R_{\theta,JC} = 0.4$ °C/W, pulse duration  $\leq 100 \, \mu s$ , duty cycle  $\leq 1\%$ 







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# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision A (April 2014) to Revision B	Page
Updated Pulsed Drain Current conditions	1
Updated the SOA in Figure 10	6
Changes from Original (January 2014) to Revision A	Page
Increased pulsed current rating to 400 A	1

Product Folder Links: CSD19536KCS

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# 5 Specifications

## 5.1 Electrical Characteristics

(T<sub>A</sub> = 25°C unless otherwise stated)

	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS		·		
BV <sub>DSS</sub>	Drain-to-Source Voltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA	100		V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 80 V		1	μΑ
I <sub>GSS</sub>	Gate-to-Source Leakage Current	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = 20 V		100	nA
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.1 2.5	3.2	V
В	Drain-to-Source On-Resistance	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 100 A	2.5	3.2	mΩ
R <sub>DS(on)</sub>	Drain-to-Source On-Resistance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 100 A	2.3	2.7	$m\Omega$
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 100 A	307		S
DYNAMI	IC CHARACTERISTICS		·		
C <sub>iss</sub>	Input Capacitance		9250	12000	pF
C <sub>oss</sub>	Output Capacitance	$V_{GS} = 0 \text{ V}, V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}$	1820	2370	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		47	61	pF
$R_G$	Series Gate Resistance		1.4	2.8	Ω
$Q_g$	Gate Charge Total (10 V)		118	153	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain	V <sub>DS</sub> = 50 V, I <sub>D</sub> = 100 A	17		nC
$Q_{gs}$	Gate Charge Gate to Source		37		nC
Q <sub>g(th)</sub>	Gate Charge at V <sub>th</sub>		24		nC
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V	335		nC
t <sub>d(on)</sub>	Turn On Delay Time		14		ns
t <sub>r</sub>	Rise Time	V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 10 V,	8		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_{DS} = 100 \text{ A}, R_G = 0 \Omega$	38		ns
t <sub>f</sub>	Fall Time		5		ns
DIODE C	CHARACTERISTICS	·			
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 100 A, V <sub>GS</sub> = 0 V	0.9	1.1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DS</sub> = 50 V, I <sub>F</sub> = 100 A,	548		nC
t <sub>rr</sub>	Reverse Recovery Time	di/dt = 300 A/µs	110		ns

#### 5.2 Thermal Information

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

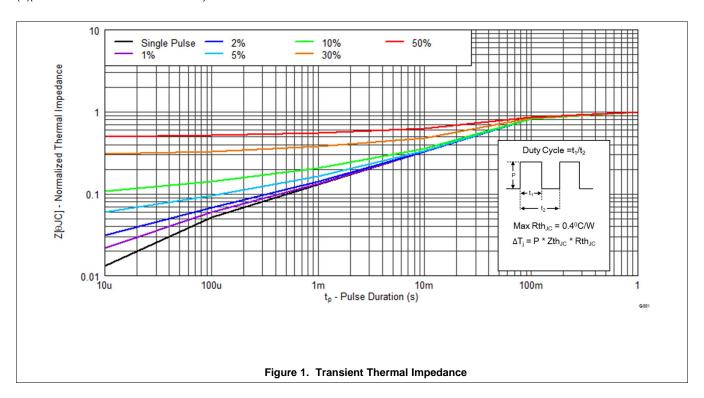
	THERMAL METRIC	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			0.4	°C/W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			62	C/VV

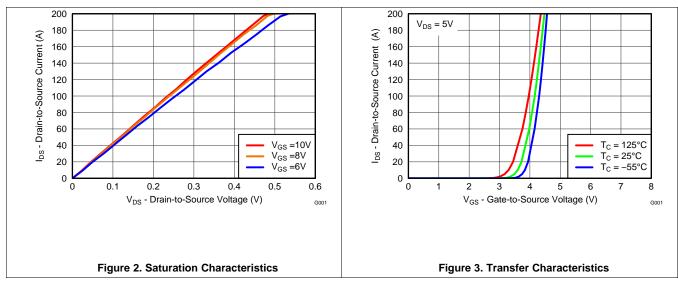
Product Folder Links: CSD19536KCS



# 5.3 Typical MOSFET Characteristics

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

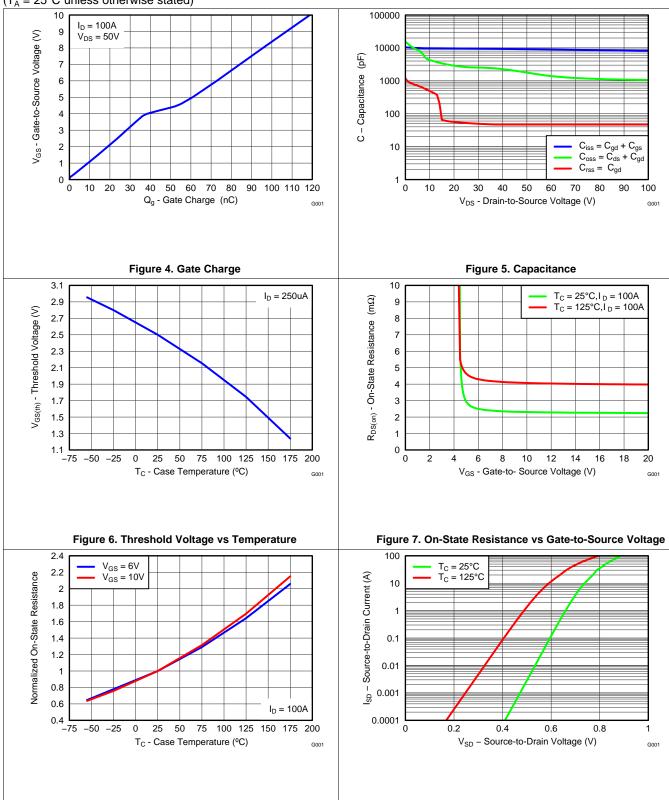






### **Typical MOSFET Characteristics (continued)**

(T<sub>A</sub> = 25°C unless otherwise stated)



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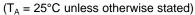
Figure 8. Normalized On-State Resistance vs Temperature

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Figure 9. Typical Diode Forward Voltage



# **Typical MOSFET Characteristics (continued)**



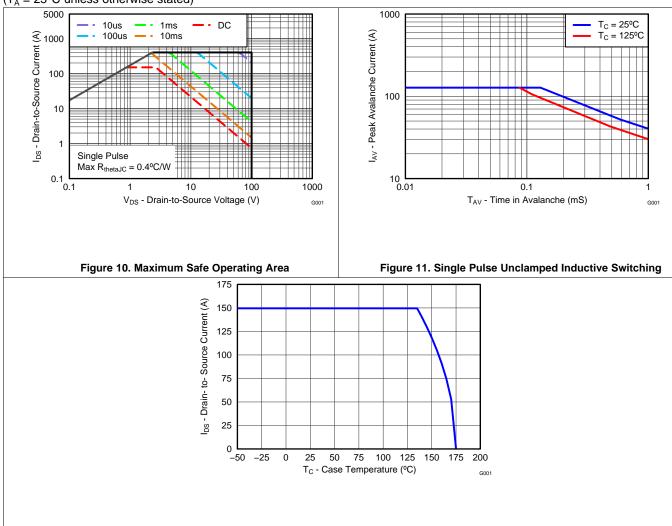


Figure 12. Maximum Drain Current vs Temperature

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# 6 Device and Documentation Support

#### 6.1 Trademarks

NexFET is a trademark of Texas Instruments.

### 6.2 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 6.3 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

Product Folder Links: CSD19536KCS



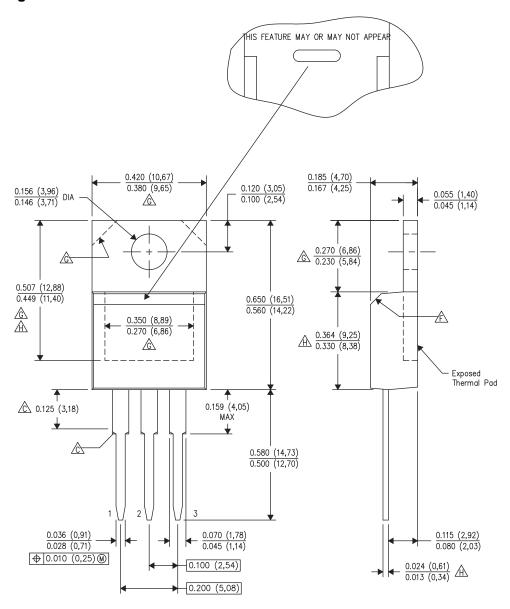
## 7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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#### 7.1 KCS Package Dimensions



NOTES: All linear dimensions are in inches (millimeters).

This drawing is subject to change without notice.

Lead dimensions are not controlled within this area. Chamfer may or may not appear D. All lead dimensions apply before solder dip. E. The center lead is in electrical contact with the mounting tab.

The center lead is in electrical contact with the mounting tab.

The chamfer is optional.

Thermal pad contour optional within these dimensions.

⚠ Falls within JEDEC TO-220 variation AB, except minimum lead thickness, minimum exposed pad length, and maximum body length.

**Pin Configuration** 

Position	Designation
Pin 1	Gate
Pin 2 / Tab	Drain
Pin 3	Source

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## PACKAGE OPTION ADDENDUM

18-Oct-2014

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD19536KCS	ACTIVE	TO-220	KCS	3	50	Pb-Free (RoHS)	CU SN	N / A for Pkg Type	-55 to 175	CSD19536KCS	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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